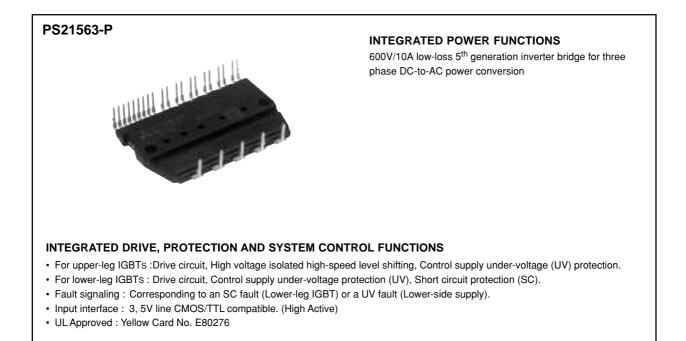
MITSUBISHI SEMICONDUCTOR < Dual-In-Line Package Intelligent Power Module>

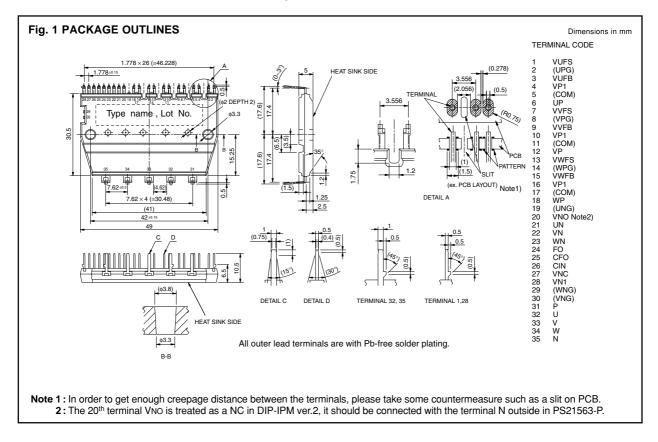
PS21563-P

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APPLICATION

AC100V~200V inverter drive for small power motor control.





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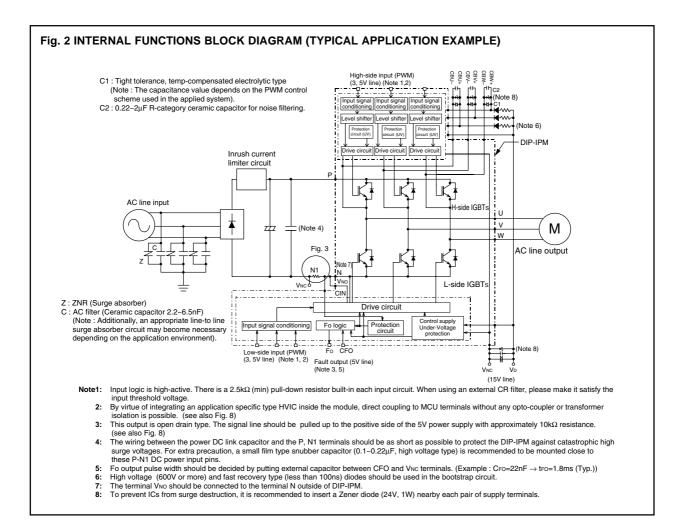
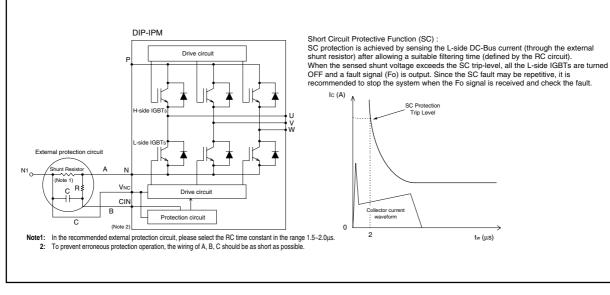


Fig. 3 EXTERNAL PART OF THE DIP-IPM PROTECTION CIRCUIT





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MAXIMUM RATINGS (Tj = 25°C, unless otherwise noted) INVERTER PART

Symbol	Parameter	Condition	Ratings	Unit
Vcc	Supply voltage	Applied between P-N	450	V
VCC(surge)	Supply voltage (surge)	Applied between P-N	500	V
VCES	Collector-emitter voltage		600	V
±IC	Each IGBT collector current	Tf = 25°C	10	A
±Іср	Each IGBT collector current (peak)	Tf = 25°C, less than 1ms	20	A
Pc	Collector dissipation	Tf = 25°C, per 1 chip	20	W
Tj	Junction temperature	(Note 1) –20~+125	°C

Note 1 : The maximum junction temperature rating of the power chips integrated within the DIP-IPM is 150°C (@ $T_f \le 100^{\circ}C$) however, to ensure safe operation of the DIP-IPM, the average junction temperature should be limited to $T_{j(ave)} \le 125^{\circ}C$ (@ $T_f \le 100^{\circ}C$).

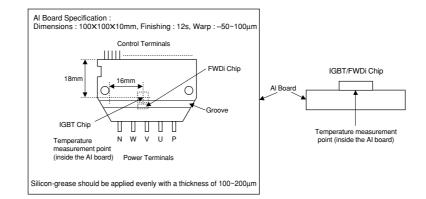
CONTROL (PROTECTION) PART

Symbol	Parameter	Condition	Ratings	Unit
Vd	Control supply voltage	Applied between VP1-VNC, VN1-VNC	20	V
Vdb	Control supply voltage	Applied between VUFB-VUFS, VVFB-VVFS, VWFB-VWFS	20	V
VIN	Input voltage	Applied between UP, VP, WP, UN, VN, WN-VNC	-0.5~VD+0.5	V
Vfo	Fault output supply voltage	Applied between FO-VNC	-0.5~VD+0.5	V
IFO	Fault output current	Sink current at Fo terminal	1	mA
Vsc	Current sensing input voltage	Applied between CIN-VNC	-0.5~VD+0.5	V

TOTAL SYSTEM

Symbol	Parameter	Condition	Ratings	Unit
VCC(PROT)	Self protection supply voltage limit (short circuit protection capability)	$V_D = 13.5 \sim 16.5 V$, Inverter part T _j = 125°C, non-repetitive, less than 2 µs	400	V
Tf	Module case operation temperature	(Note 2)	-20~+100	°C
Tstg	Storage temperature		-40~+125	°C
Viso	Isolation voltage	60Hz, Sinusoidal, 1 minute, All connected pins to heat-sink plate	2500	Vrms

Note 2 : Tf measurement point





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THERMAL RESISTANCE

Cumhal	Devementer	Condition		Limits		
Symbol Parameter		Condition		Тур.	Max.	Unit
Rth(j-f)Q	Junction to case thermal	Inverter IGBT part (per 1/6 module)	_	_	5.0	°C/W
Rth(j-f)F	resistance (Note 3)	Inverter FWD part (per 1/6 module)	_	_	6.5	°C/W

Note 3: Grease with good thermal conductivity should be applied evenly with about +100µm~+200µm on the contacting surface of DIP-IPM and heat-sink.

ELECTRICAL CHARACTERISTICS (Tj = 25°C, unless otherwise noted) **INVERTER PART**

Symbol Parameter		Condition		Limits			Unit
Symbol	Parameter		Condition		Тур.	Max.	Unit
VCE(sat)	Collector-emitter saturation	VD = VDB = 15V	VD = VDB = 15V IC = 10A, Tj = 25°C		1.60	2.10	V
VCE(Sal)	voltage	VIN = 5V	IC = 10A, Tj = 125°C	-	1.70	2.20	V
VEC	FWD forward voltage	$T_j = 25^{\circ}C, -IC = 10A, VIN = 0V$		-	1.50	2.00	V
ton		Vcc = 300V, VD = VDB = 15V		0.60	1.20	1.80	μs
trr				-	0.30	—	μs
tc(on)	Switching times	IC = 10A, Tj = 125°C, VIN = $0 \leftrightarrow 5V$		—	0.40	0.60	μs
toff]	Inductive load (upper-log	Inductive load (upper-lower arm)		1.40	2.10	μs
tc(off)				—	0.50	0.80	μs
ICES	Collector-emitter cut-off	VCE = VCES	$T_j = 25^{\circ}C$	_	_	1	mA
1020	current	VUE = VUES	Tj = 125°C	_	_	10	

CONTROL (PROTECTION) PART

Symbol	Parameter	Condition		Limits			Unit		
Symbol	Farameter		Cor	Idition		Min.	Тур.	Max.	Unit
ID Circu		VD = VDB = 15V	Total o	f Vp1-VNC, VN1-VNC		—	—	5.00	
	Circuit current	VIN = 5V	VUFB-\	/UFS, VVFB-VVFS, VW	FB-VWFS	—	—	0.40 mA	
ID		VD = VDB = 15V	Total of	f Vp1-VNC, VN1-VNC		—	—	7.00	IIIA
		VIN = 0V	VUFB-V	UFS, VVFB-VVFS, VWF	-B-VWFS	—	_	0.55	
VFOH	Fault output voltage	Vsc = 0V, Fo circuit pull-up to 5V with $10k\Omega$		4.9	_	—	V		
VFOL	Fault output voltage	VSC = 1V, IFO = 1mA		—	—	0.95	V		
VSC(ref)	Short circuit trip level	$T_f = -20 \sim 100^{\circ}C, V_D = 15V$ (Note 4)		0.45	—	0.52	V		
lin	Input current	VIN = 5V		1.0	1.5	2.0	mA		
UVDBt				Trip level		10.0	_	12.0	V
UVDBr	Control supply under-voltage			Reset level		10.5	—	12.5	V
UVDt	protection	1]≤125°0		Trip level		10.3	_	12.5	V
UVDr		Reset		Reset level		10.8	—	13.0	V
tFO	Fault output pulse width	CFO = 22nF (Note 5)		1.0	1.8	_	ms		
Vth(on)	ON threshold voltage			2.1	2.3	2.6	V		
Vth(off)	OFF threshold voltage	Applied between UP, VP, WP-VNC, UN, VN, WN-VNC			NC	0.8	1.4	2.1	V

Note 4: Short circuit protection is functioning only for the lower-arms. Please select the external shunt resistance such that the SC trip-level is less than 2.0 times of the current rating.
5: Fault signal is asserted corresponding to a short circuit or lower side control supply under-voltage failure. The fault output pulse width tFO depends on the capacitance value of CFO according to the following approximate equation : CFO = 12.2 × 10⁻⁶ × tFO [F].

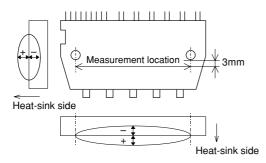


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MECHANICAL CHARACTERISTICS AND RATINGS

Deremeter	Con	Limits			Unit	
Parameter	Condition			Тур.	Max.	Unit
Mounting torque	Mounting screw : M3 Recommended : 0.78 N·m			—	0.98	N∙m
Weight			—	20	—	g
Heat-sink flatness	(Note 6)		-50	_	100	μm

Note 6: Measurement point of heat-sink flatness



RECOMMENDED OPERATION CONDITIONS

O wash al	Parameter Condition		Reco	mmended	value	Unit	
Symbol Parameter		Condition		Min.	Тур.		Max.
Vcc	Supply voltage	Applied between P-N		0	300	400	V
Vd	Control supply voltage	Applied between VP1-VNC, VN1-VN	C	13.5	15.0	16.5	V
Vdb	Control supply voltage	Applied between VUFB-VUFS, VVFB	-VVFS, VWFB-VWFS	13.0	15.0	18.5	V
ΔV d, ΔV db	Control supply variation			-1	—	1	V/µs
tdead	Arm shoot-through blocking time	For each input signal, Tf ≤ 100°C			—	_	μs
fpwm	PWM input frequency	Tf ≤ 100°C, Tj ≤ 125°C		—	—	20	kHz
	VCC = 300V, VD = VDB = 15V,	fPWM = 5kHz	—	—	6.5		
lo	Allowable r.m.s. current $P.F = 0.8$, sinusoidal output $T_f \le 100^{\circ}C$, $T_i \le 125^{\circ}C$ (Note 7)	fPWM = 15kHz	_	_	4.0	Arms	
PWIN(on)			(Note 8)	0.3		_	
		$200 \le Vcc \le 350V$, $13.5 \le VD \le 16.5V$,	Below rated current	0.5	_	_	
Allowable minimum ir PWIN(off) pulse width	Allowable minimum input pulse width	$13.0 \le VDB \le 18.5V,$ -20°C $\le Tf \le 100°C,$	Between rated current and 1.7 times of rated current	0.5	_	_	μs
		N-line wiring inductance less than 10nH (Note 9)	Between 1.7 times and 2.0 times of rated current	0.7	_	_	
VNC	VNC variation	Between VNC-N (including surge)		-5.0	_	5.0	V

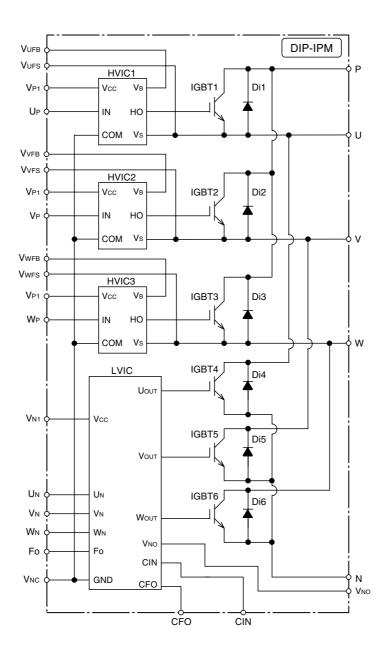
Note 7: The allowable r.m.s. current value depends on the actual application conditions.
8: The input pulse width less than PWIN(on) might make no response.
9: IPM might not work properly or make response for the input signal with OFF pulse width less than PWIN(off). Please refer to Fig.7.



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INSULATED TYPE

Fig. 4 THE DIP-IPM INTERNAL CIRCUIT



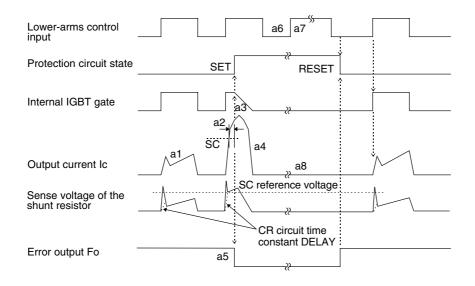


TRANSFER-MOLD TYPE INSULATED TYPE

Fig. 5 TIMING CHART OF THE DIP-IPM PROTECTIVE FUNCTIONS

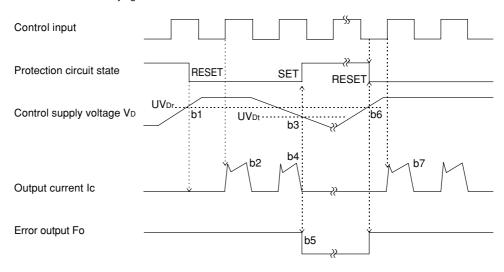
[A] Short-Circuit Protection (Lower-arms only with the external shunt resistor and CR filter)

- a1. Normal operation : IGBT ON and carrying current.
- a2. Short circuit current detection (SC trigger).
- a3. IGBT gate hard interruption.
- a4. IGBT turns OFF.
- a5. FO timer operation starts : The pulse width of the FO signal is set by the external capacitor CFO.
- a6. Input "L" : IGBT OFF. a7. Input "H" : IGBT ON.
- a8. IGBT OFF in spite of input "H".



[B] Under-Voltage Protection (Lower-arm, UVD)

- b1. Control supply voltage rises : After the voltage level reaches UVDr, the circuits start to operate when next input is applied.
- b2. Normal operation : IGBT ON and carrying current.
- b3. Under voltage trip (UVDt).
- b4. IGBT OFF in spite of control input condition.
- b5. Fo operation starts.
- b6. Under voltage reset (UVDr).
- b7. Normal operation : IGBT ON and carrying current.





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[C] Under-Voltage Protection (Upper-arm, UVDB)

- c1. Control supply voltage rises : After the voltage reaches UVDBr, the circuits start to operate when next input is applied. c2. Normal operation : IGBT ON and carrying current.
- c3. Under voltage trip (UVDBt).
- c4. IGBT OFF in spite of control input condition, but there is no Fo signal output.
- c5. Under voltage reset (UVDBr)
- c6. Normal operation : IGBT ON and carrying current.

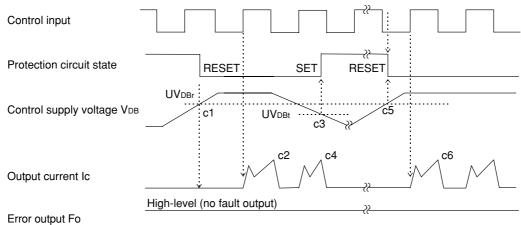
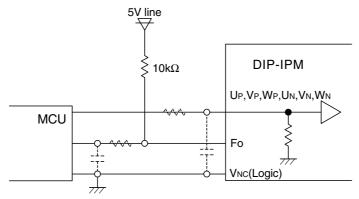


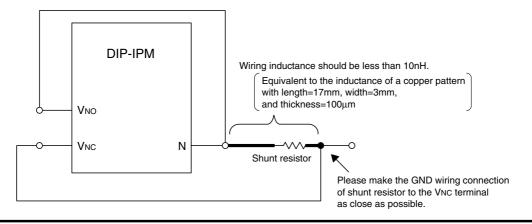
Fig. 6 RECOMMENDED CPU I/O INTERFACE CIRCUIT



Note : The setting of RC coupling at each input (parts shown dotted) depends on the PWM control scheme and the wiring impedance of the printed circuit board.

The DIP-IPM input section integrates a $2.5 k\Omega$ (min) pull-down resistor. Therefore, when using an external filtering resistor, pay attention to the turn-on threshold voltage.

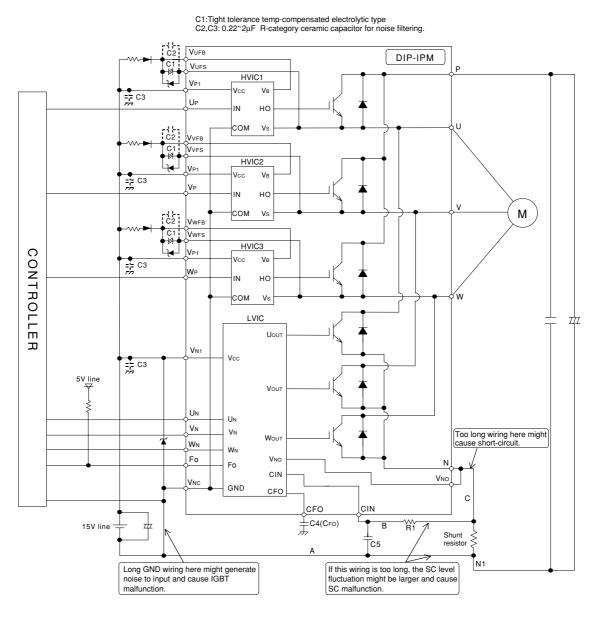
Fig. 7 WIRING CONNECTION OF SHUNT RESISTOR





TRANSFER-MOLD TYPE INSULATED TYPE

Fig. 8 TYPICAL DIP-IPM APPLICATION CIRCUIT EXAMPLE



Note 1: To prevent the input signals oscillation, the wiring of each input should be as short as possible. (Less than 2cm)

- 2: By virtue of integrating an application specific type HVIC inside the module, direct coupling to MCU terminals without any opto-coupler or transformer isolation is possible.
- 3: Fo output is open drain type. This signal line should be pulled up to the positive side of the 5V power supply with approximately 10kΩ resistor.
- 4: FO output pulse width is determined by the external capacitor between CFO and VNC terminals (CFO). (Example : CFO = 22 nF \rightarrow tFO = 1.8 ms (typ.))
- 5: The logic of input signal is high-active. The DIP-IPM input signal section integrates a 2.5kΩ (min) pull-down resistor. Therefore, when using external filtering resistor, care must be taken to satisfy the turn-on threshold voltage requirement.
- 6: To prevent malfunction of protection, the wiring of A, B, C should be as short as possible.
- 7: Please set the C5R1 time constant in the range $1.5 \sim 2\mu s$.
- 8: Each capacitor should be located as nearby the pins of the DIP-IPM as possible.
- **9**: To prevent surge destruction, the wiring between the smoothing capacitor and the P, N1 pins should be as short as possible. Approximately a 0.1~0.22μF snubber capacitor between the P-N1 pins is recommended.
- 10: The terminal VNO should be connected with the terminal N outside.
- 11: To prevent ICs from surge destruction, it is recommended to insert a Zener diode (24V, 1W) nearby each pair of supply terminals.

